INTEGRATED CIRCUITS

DATA SHEET

74ABT20Dual 4-input NAND gate

Product specification

1995 Sep 22

IC23 Data Handbook





Philips

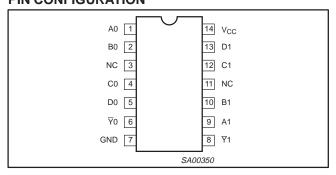
Semiconductors

74ABT20

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS $T_{amb} = 25^{\circ}C;$ $GND = 0V$ | TYPICAL | UNIT |
|--------------------------------------|--|--|------------|------|
| t _{PLH} t _{PHL} | Propagation delay An, Bn, Cn, Dn to \overline{Y} n $C_L = 50pF;$ $V_{CC} = 5V$ | | 2.7 2.2 | ns |
| toslh toshl | Output to Output skew | | 0.3 | ns |
| C _{IN} | Input capacitance | V _I = 0V or V _{CC} | 3 | pF |
| I _{CC} | Total supply current Outputs disabled; $V_{CC} = 5.5V$ | | 50 | μΑ |

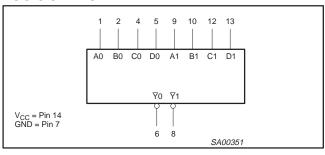
PIN CONFIGURATION



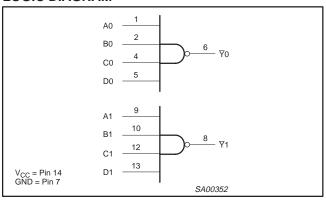
PIN DESCRIPTION

| PIN NUMBER | SYMBOL | NAME AND FUNCTION |
|------------------------------|-------------------|-------------------------|
| 1, 2, 4, 5, 9, 10, 12, 13 | An, Bn, Cn, Dn | Data inputs |
| 6, 8 | ₹n | Data outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive supply voltage |

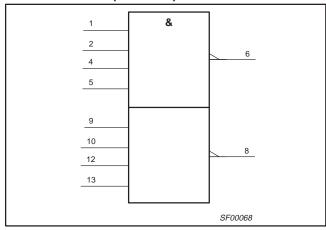
LOGIC SYMBOL



LOGIC DIAGRAM



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

| | INP | UTS | | OUTPUT |
|----|-----|-----|----|--------|
| An | Bn | Cn | Dn | ₹n |
| L | Х | Х | Х | Н |
| Х | L | Х | Х | Н |
| Х | Х | L | Х | Н |
| Х | Х | Х | L | Н |
| Н | Н | Н | Н | L |

NOTES:

H = High voltage levelL = Low voltage level

X = Don't care

ORDERING INFORMATION

| PACKAGES | TEMPERATURE RANGE | OUTSIDE NORTH AMERICA | NORTH AMERICA | DWG NUMBER |
|-----------------------------|-------------------|-----------------------|---------------|------------|
| 14-Pin Plastic DIP | -40°C to +85°C | 74ABT20 N | 74ABT20 N | SOT27-1 |
| 14-Pin plastic SO | –40°C to +85°C | 74ABT20 D | 74ABT20 D | SOT108-1 |
| 14-Pin Plastic SSOP Type II | -40°C to +85°C | 74ABT20 DB | 74ABT20 DB | SOT337-1 |
| 14-Pin Plastic TSSOP Type I | -40°C to +85°C | 74ABT20 PW | 74ABT20PW DH | SOT402-1 |

Philips Semiconductors Product specification

Dual 4-input NAND gate

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ABSOLUTE MAXIMUM RATINGS1, 2

| SYMBOL | PARAMETER | CONDITIONS | RATING | UNIT |
|------------------|--------------------------------|-----------------------------|--------------|------|
| V _{CC} | DC supply voltage | | -0.5 to +7.0 | V |
| I _{IK} | DC input diode current | V _I < 0 | -18 | mA |
| V _I | DC input voltage ³ | | -1.2 to +7.0 | V |
| I _{OK} | DC output diode current | V _O < 0 | -50 | mA |
| V _{OUT} | DC output voltage ³ | output in Off or High state | -0.5 to +5.5 | V |
| I _{OUT} | DC output current | output in Low state | 40 | mA |
| T _{stg} | Storage temperature range | | -65 to 150 | °C |

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
 device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
 absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | LIM | ITS | UNIT | |
|------------------|--------------------------------------|-----|-----------------|------|--|
| STWIBOL | FARAMETER | MIN | MAX | | |
| V _{CC} | DC supply voltage | 4.5 | 5.5 | V | |
| VI | Input voltage | 0 | V _{CC} | V | |
| V _{IH} | High-level input voltage | 2.0 | | V | |
| V_{IL} | Low-level input voltage | | 0.8 | V | |
| I _{OH} | High-level output current | | -15 | mA | |
| I _{OL} | Low-level output current | | 20 | mA | |
| Δt/Δν | Input transition rise or fall rate | 0 | 10 | ns/V | |
| T _{amb} | Operating free-air temperature range | -40 | +85 | °C | |

DC ELECTRICAL CHARACTERISTICS

| | | | | | LIMITS | | | |
|------------------|--|--|-----|---------------------|--------|--------------------|---------------|------|
| SYMBOL | PARAMETER | TEST CONDITIONS | Tai | _{mb} = +25 | 5°C | T _{amb} = | -40°C 85°C | UNIT |
| | | | MIN | TYP | MAX | MIN | MAX | 1 |
| V _{IK} | Input clamp voltage | $V_{CC} = 4.5V; I_{IK} = -18mA$ | | -0.9 | -1.2 | | -1.2 | V |
| V _{OH} | High-level output voltage | $V_{CC} = 4.5V$; $I_{OH} = -15mA$; $V_I = V_{IL}$ or V_{IH} | 2.5 | 2.9 | | 2.5 | | V |
| V _{OL} | Low-level output voltage | $V_{CC} = 4.5V$; $I_{OL} = 20mA$; $V_I = V_{IL}$ or V_{IH} | | 0.35 | 0.5 | | 0.5 | V |
| II | Input leakage current | $V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$ | | ±0.01 | ±1.0 | | ±1.0 | μΑ |
| I _{OFF} | Power-off leakage current | $V_{CC} = 0.0V$; V_O or $V_I \le 4.5V$ | | ±5.0 | ±100 | | ±100 | μΑ |
| I _{CEX} | Output High leakage current | $V_{CC} = 5.5V$; $V_O = 5.5V$; $V_I = GND$ or V_{CC} | | 5.0 | 50 | | 50 | μΑ |
| ΙO | Output current ¹ | V _{CC} = 5.5V; V _O = 2.5V | -50 | -75 | -180 | -50 | -180 | mA |
| I _{CC} | Quiescent supply current | $V_{CC} = 5.5V$; $V_I = GND$ or V_{CC} | | 2 | 50 | | 50 | μΑ |
| Δl _{CC} | Additional supply current per input pin ² | V_{CC} = 5.5V; One data input at 3.4V, other inputs at V_{CC} or GND | | 0.25 | 500 | | 500 | μА |

NOTES

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- 2. This is the increase in supply current for each input at 3.4V.
- 3. For valid test results, data must not be loaded into the flip-flop or latch after applying the power.

74ABT20

AC CHARACTERISTICS

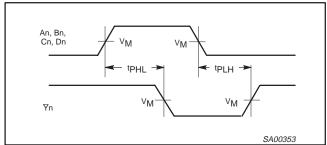
GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF, R_L = 500 Ω

| SYMBOL | PARAMETER | WAVEFORM | T _a | _{amb} = +25° ' _{CC} = +5.0' | C V | T _{amb} = -40° V _{CC} = +5. | UNIT | |
|--------------------------------------|---|----------|----------------|--|------------|--|------------|----|
| | | | MIN | TYP | MAX | MIN | MAX | |
| t _{PLH} t _{PHL} | Propagation delay An, Bn, Cn, Dn to Yn | 1 | 1.0 1.0 | 2.7 2.2 | 3.9 3.4 | 1.0 1.0 | 4.6 3.8 | ns |
| toshl toshh1 | Output to Output skew An or Bn to Yn | 2 | | 0.3 | 0.5 | | 0.5 | ns |

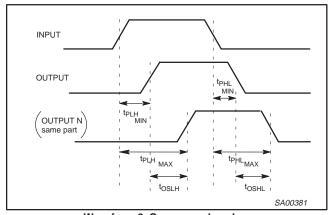
NOTE:

AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$

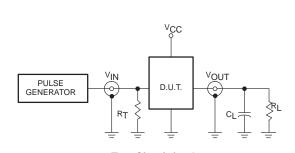


Waveform 1. Propagation Delay for Inverting Outputs



Waveform 2. Common edge skew

TEST CIRCUIT AND WAVEFORMS



Test Circuit for Outputs

Input Pulse Definition

| FAMILY | INPUT PULSE REQUIREMENTS | | | | | | | | | | | |
|--------|--------------------------|-----------|----------------|----------------|----------------|--|--|--|--|--|--|--|
| PAWILY | Amplitude | Rep. Rate | t _W | t _R | t _F | | | | | | | |
| 74ABT | 3.0V | 1MHz | 500ns | 2.5ns | 2.5ns | | | | | | | |

SH00067

DEFINITIONS

- R_L = Load resistor; see AC CHARACTERISTICS for value.
- $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.
- R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

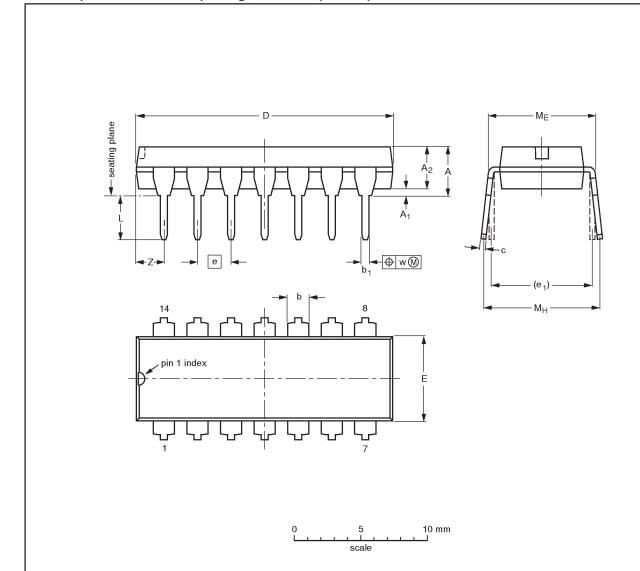
1995 Sep 22

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | С | D ⁽¹⁾ | E ⁽¹⁾ | е | e ₁ | L | ME | M _H | w | Z ⁽¹⁾ max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|--------------|----------------|-------|--------------------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.020 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.10 | 0.30 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

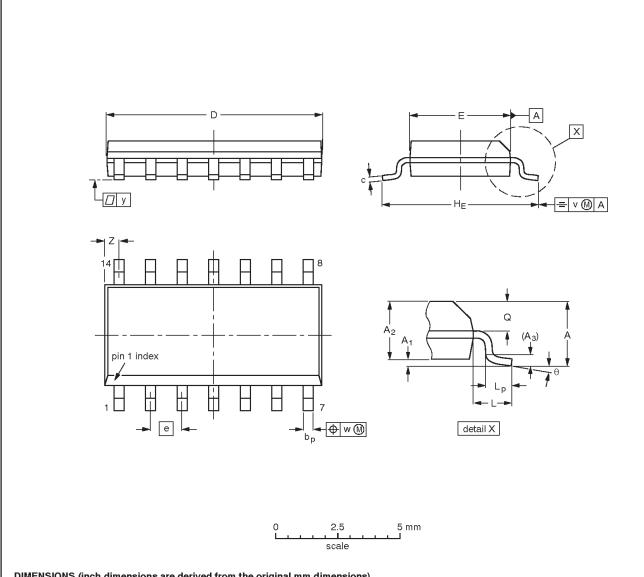
| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | |
|---------|--------|----------|------------|------------|--|---------------------------------|
| VERSION | IEC | JEDEC | PROJECTION | 1330E DATE | | |
| SOT27-1 | 050G04 | MO-001AA | | | | 92-11-17 95-03-11 |

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74ABT20

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|--------|-----------|----------------|----------------|----------------|--------------|------------------|------------------|------------------|-------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm | 1.75 | 0.25 0.10 | 1.45 1.25 | 0.25 | 0.49 0.36 | 0.25 0.19 | 8.75 8.55 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8° |
| inches | 0.069 | 0.010 0.004 | 0.057 0.049 | 0.01 | | 0.0100 0.0075 | | 0.16 0.15 | 0.050 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.024 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | 0° |

Note

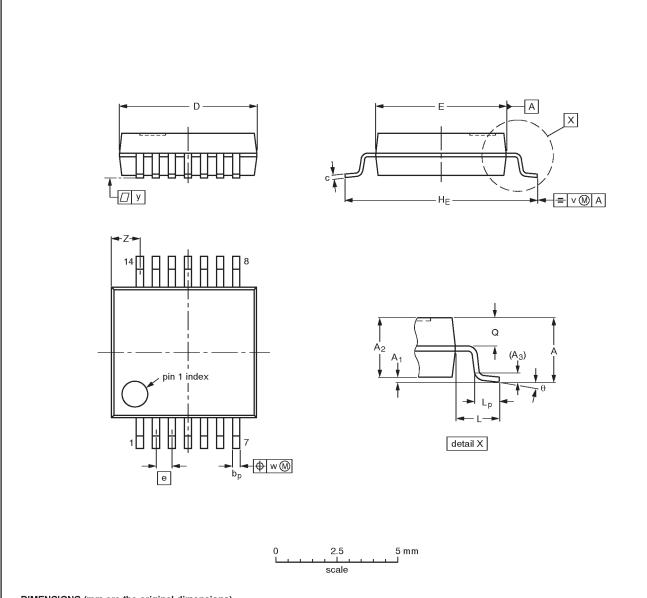
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE | | EUROPEAN | ISSUE DATE | | | | |
|----------|---------|----------|------------|--|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE | |
| SOT108-1 | 076E06S | MS-012AB | | | | 95-01-23 97-05-22 | |

74ABT20

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | рb | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|-----------------------|--------------|--------------|------------------|------------------|------|------------|------|--------------|------------|-----|------|-----|------------------|----------|
| mm | 2.0 | 0.21 0.05 | 1.80 1.65 | 0.25 | 0.38 0.25 | 0.20 0.09 | 6.4 6.0 | 5.4 5.2 | 0.65 | 7.9 7.6 | 1.25 | 1.03 0.63 | 0.9 0.7 | 0.2 | 0.13 | 0.1 | 1.4 0.9 | 8° 0° |

Note

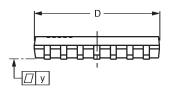
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

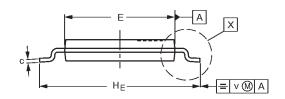
| OUTLINE | | EUROPEAN | ISSUE DATE | | | |
|----------|-----|----------|------------|--|------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT337-1 | | MO-150AB | | | | -95-02-04 96-01-18 |

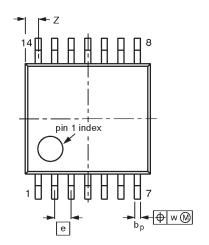
74ABT20

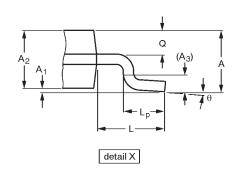
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

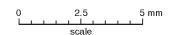
SOT402-1











DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | Α1 | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽²⁾ | е | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|--------------|----------------|----------------|--------------|------------|------------------|------------------|------|------------|-----|--------------|------------|-----|------|-----|------------------|----------|
| mm | 1.10 | 0.15 0.05 | 0.95 0.80 | 0.25 | 0.30 0.19 | 0.2 0.1 | 5.1 4.9 | 4.5 4.3 | 0.65 | 6.6 6.2 | 1.0 | 0.75 0.50 | 0.4 0.3 | 0.2 | 0.13 | 0.1 | 0.72 0.38 | 8° 0° |

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | RENCES | EUROPEAN | | | | | |
|----------|-----|--------|--------|------------|---------------------------------|--|--|--|--|
| VERSION | IEC | JEDEC | EIAJ | PROJECTION | ISSUE DATE | | | | |
| SOT402-1 | | MO-153 | | | 94-07-12 95-04-04 | | | | |

Philips Semiconductors Product specification

Dual 4-input NAND gate

74ABT20

NOTES

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Philips Semiconductors Product specification

Dual 4-input NAND gate

74ABT20

| DEFINITIONS | | | | | | | |
|---------------------------|------------------------|--|--|--|--|--|--|
| Data Sheet Identification | Product Status | Definition | | | | | |
| Objective Specification | Formative or in Design | This data sheet contains the design target or goal specifications for product development. Specificati may change in any manner without notice. | | | | | |
| Preliminary Specification | Preproduction Product | This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product. | | | | | |
| Product Specification | Full Production | This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make change at any time without notice, in order to improve design and supply the best possible product. | | | | | |

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